HAMAMATSU

PHOTOMULTIPLIER TUBE **R7154**

High Sensitivity Solar Blind Photocathode (160 nm to 320 nm) 28 mm (1-1/8 lnch) Diameter, 9-Stage, Side-On Type

FEATURES

●Spectral Response	160 nm to 320 nm
●Cathode Sensitivity	
Radiant at 254 nm	62 mA/W Typ.
Quantum Efficiency at 254 nm	30 % Typ.
●Anode Sensitivity (at 1000 V)	

Radiant at 254 nm 6.2×10^5 A/W Typ.



APPLICATIONS

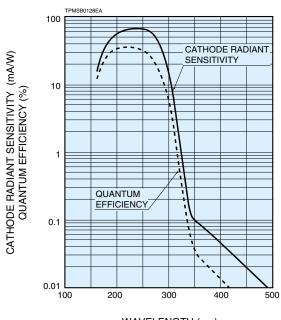
- **●**Emission Spectroscopy
- **OUV Spectrophotometers**

SPECIFICATIONS

GENERAL

Pa	rameter	Description/Value	Unit	
Spectral Response		160 to 320	nm	
Wavelength of Maximum Response		254	nm	
Photocathode	Material	Cs-Te	_	
Filolocalilode	Minimum Effective Area	8 × 24	mm	
Window Materi	al	Quartz	_	
	Secondary Emitting Surface	Sb-Cs	_	
Dynode	Structure	Circular-cage	_	
	Number of Stages	9	_	
Direct Interelectrode	Anode to Last Dynode	4	pF	
Capacitances	Anode to All Other Electrodes	6	pF	
Base		11-pin base JEDEC No. B11-88	_	
Weight		Approx. 45	g	
Operating Ambient Temperature		-30 to +50	°C	
Storage Temperature		-30 to +50	°C	
Suitable Socket		E678–11A (Sold Separately)	_	
Suitable Socke	t Accombly	E717–63 (Sold Separately)		
Suitable Socke	a Assembly	E717–74 (Sold Separately)		

Figure 1: Typical Spectral Response



WAVELENGTH (nm)

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MAXIMUM RATINGS (Absolute Maximum Values)

	Parameter	Value	Unit
Supply Voltage Between Anode and Cathode		1250	V
Supply voltage	Between Anode and Last Dynode	250	٧
Average Anode Current ^A		0.1	mA

CHARACTERISTICS (at 25 °C)

	Parameter		Min.	Тур.	Max.	Unit
Cathode Sensitivity	Quantum Efficiency at 254 nm		_	30	_	%
Radiant at		at 254 nm	_	62	_	mA/W
Anode Sensitivity	Radiant	at 254 nm	1.0×10^5	6.2×10^{5}	_	A/W
Gain		_	1.0×10^{7}	_	_	
Anode Dark Current F (After 30 min Storage in Darkness)		_	1	10	nA	
ENI (Equivalent Noise Input) G		_	9.1 × 10 ⁻¹⁷	_	W	
	Anode Pulse Rise Time H		_	2.2	_	ns
Time Response E	Electron Transit Time	e	_	22	_	ns
	Transit Time Spread	(TTS) J	_	1.2	_	ns
Anada Current Stability K	Light Hysteresis		_	0.1	_	%
Anode Current Stability K	Voltage Hysteresis		<u> </u>	1.0	_	%

NOTES

- A: Averaged over any interval of 30 seconds maximum.
- B: The light source is a tungsten filament lamp operated at a distribution temperature of 2856K. Supply voltage is 100 V between the cathode and all other electrodes connected together as anode.
- C:Red/White ratio is the quotient of the cathode current measured using a red filter (Toshiba R-68) interposed between the light source and the tube by the cathode current measured with the filter removed under the same conditions as Note B.
- D:The value is cathode output current when a blue filter (Corning CS 5-58 polished to 1/2 stock thickness) is interposed between the light source and the tube under the same condition as Note B.
- E: Measured with the same light source as Note B and with the voltage distribution ratio shown in Table 1 below.

Table 1: Voltage Distribution Ratio

Distribution	Electrode	K	Dy	/1	Dy	2	Dy	B D	y4	Dy	/5	Dy	⁄ 6	Dy7	' D	y8	D	у9		Р
		1		1	ı	1		1		1	-	1	1	1	1		1	1	ı	

Supply Voltage: 1000 V, K: Cathode, Dy: Dynode, P: Anode

- F: Measured with the same supply voltage and voltage distribution ratio as Note E after removal of light.
- G:ENI is an indication of the photon-limited signal-to-noise ratio. It refers to the amount of light in watts to produce a signal-to-noise ratio of unity in the output of a photomultiplier tube.

$$ENI = \frac{\sqrt{2q \cdot Idb \cdot G \cdot \Delta f}}{S}$$

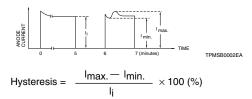
where $q = Electronic charge (1.60 \times 10^{-19} coulomb)$.

ldb = Anode dark current (after 30 minute storage) in amperes.

G = Gain.

- Δf = Bandwidth of the system in hertz. 1 hertz is used.
- S = Anode radiant sensitivity in amperes per watt at the wavelength of peak response.

- H:The rise time is the time for the output pulse to rise from 10 % to 90 % of the peak amplitude when the entire photocathode is illuminated by a delta function light pulse.
- I: The electron transit time is the interval between the arrival of delta function light pulse at the entrance window of the tube and the time when the anode output reaches the peak amplitude. In measurement, the whole photocathode is illuminated.
- J: Also called transit time jitter. This is the fluctuation in electron transit time between individual pulses in the signal photoelectron mode, and may be defined as the FWHM of the frequency distribution of electron transit times.
- K: Hysteresis is temporary instability in anode current after light and voltage are applied.



(1) Light Hysteresis

The tube is operated at 750 V with an anode current of 1 μ A for 5 minutes. The light is then removed from the tube for a minute. The tube is then re-illuminated by the previous light level for a minute to measure the variation.

(2) Voltage Hysteresis

The tube is operated at 300 V with an anode current of 0.1 μ A for 5 minutes. The light is then removed from the tube and the supply voltage is quickly increased to 800 V. After a minute, the supply voltage is then reduced to the previous value and the tube is re-illuminated for a minute to measure the variation.

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Figure 2: Anode Radiant Sensitivity and Gain Characteristcs

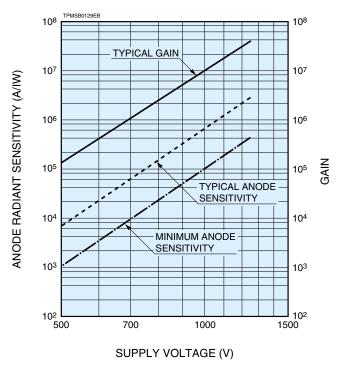
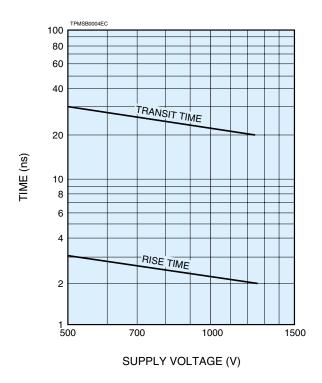


Figure 3: Typical Time Response



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Figure 4: Dimensional Outline and Basing Diagram (Unit: mm)

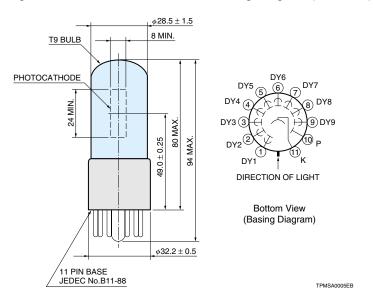
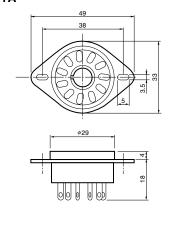


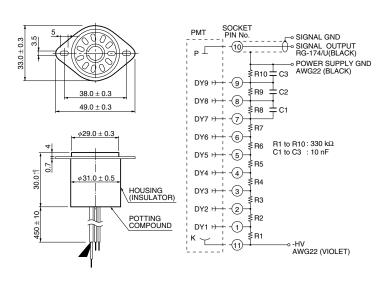
Figure 5: Socket (Unit: mm) Sold Separately

E678-11A

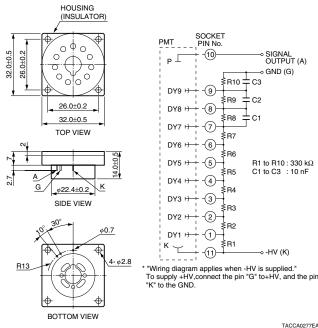


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Figure 6: D Type Socket Assembly (Unit: mm) Sold Separately **E717-63**



E717-74



* Hamamatsu also provides C4900 series compact high voltage power supplies and C6270 series DP type socket assemblies which incorporate a DC to DC converter type high voltage power supply.

Warning-Personal Safety Hazards

Electrical Shock–Operating voltages applied to this device present a shock hazard.

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